

# Features

- BVCEO > 40V
- Small Form Factor Thermally Efficient Package.
  Enables Higher Density End Products
- Ic = 2A High Continuous Collector Current
- ICM = 3A Peak Pulse Current
- Low Saturation Voltage V<sub>CE(sat)</sub> < 220mV @ 1A</li>
- Complementary PNP Type: DXTP22040CFG
- Wettable Flank for Improved Optical Inspection
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

PowerDI3333-8 (SWP) (Type UX)

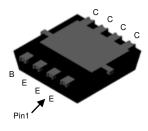
### Mechanical Data

- Case: PowerDI<sup>®</sup>3333-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.03 grams (Approximate)

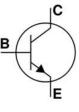
### Applications

- DC to DC Conversion
- Supply Line Switching
- Low Drop Out Regulation
- LCD Backlighting

Top View



Bottom View



**Device Symbol** 

# **Ordering Information**

Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
DXTN22040CFG-7	Standard	2K5	7	12	2,000

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

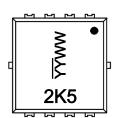
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

# **Marking Information**

PowerDI3333-8 (SWP) (Type UX)



2K5 = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 21 = 2021) WW = Week Code (01 to 53)

PowerDI is a registered trademark of Diodes Incorporated.



# Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Collector-Base Voltage	VCBO	50	V	
Collector-Emitter Voltage	V <sub>CEO</sub>	40	V	
Emitter-Base Voltage	VEBO	7	V	
Continuous Collector Current	lc	2	٨	
Peak Pulse Collector Current	Ісм	3	A	
Continuous Base Current	IB	100	m ^	
Peak Pulse Base Current	Івм	200	- mA	

# **Thermal Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Power Dissipation	(Note 5)	D-	1.1	W
Power Dissipation	(Note 6)	PD PD	2.3	W
Thermal Desistance Junction to Ambient	(Note 5)	Р	113	°C/W
Thermal Resistance, Junction to Ambient	(Note 6)	- Reja	55	°C/W
Thermal Resistance, Junction to Leads (Note 7)		R <sub>0JL</sub>	7.4	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

#### ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge – Human Body Model	ESD HBM	4,000	V	ЗA
Charge Device Model	CDM	1,000	V	C5

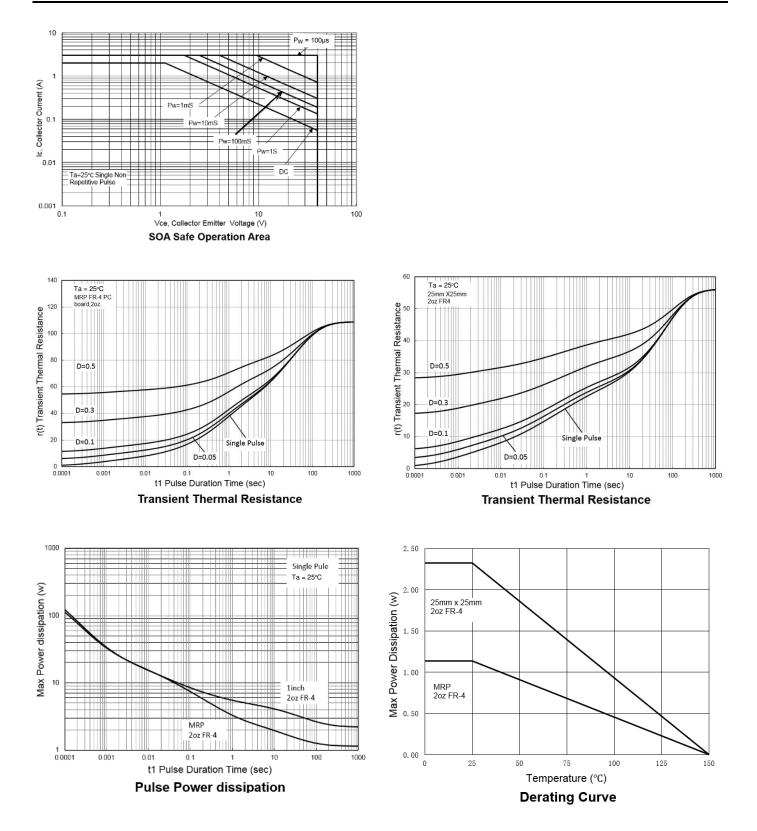
Notes: 5. For a device mounted with the collector tab on MRP FR4-PCB; device is measured under still air conditions whilst operating in a steady-state.

6. Same as Note 5, except the device is mounted on 25mm x 25mm 2oz copper.

Thermal resistance from junction to solder-point (at the collector tab).
 Refer to JEDEC specification JESD22-A114 and JESD22-A115.



# **Thermal Characteristics and Derating Information**





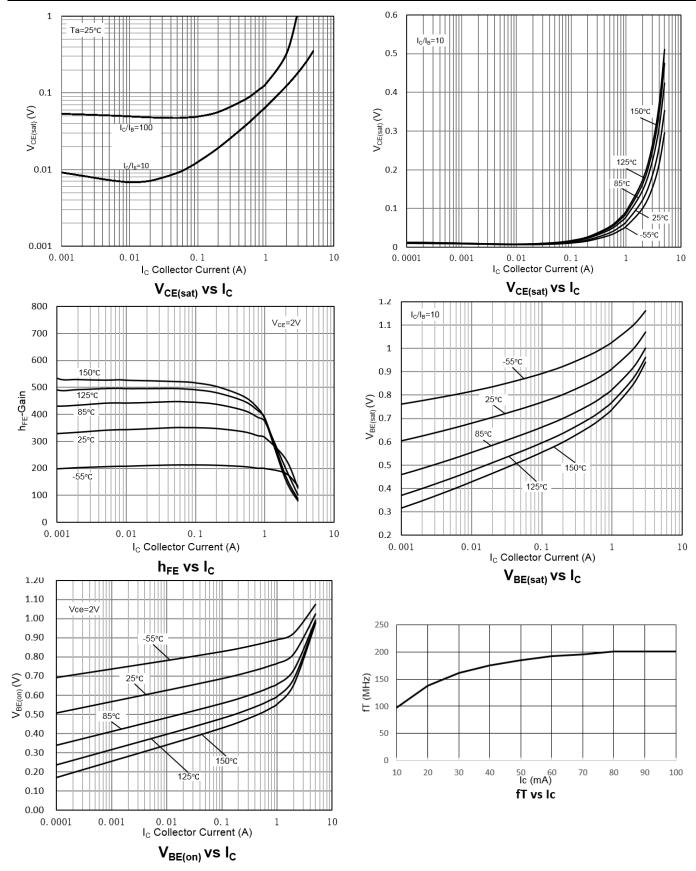
# Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	ВУсво	50	172	_	V	$I_{C} = 100 \mu A$
Collector-Emitter Breakdown Voltage (Note 9)	BVCEO	40	54	_	V	$I_{\rm C} = 10 \text{mA}$
Emitter-Base Breakdown Voltage	BVEBO	7	8		V	I <sub>E</sub> = 100μA
Collector-Base Cut-Off Current	I <sub>CBO</sub>	_	1.5 0.06	50 20	nA μA	V <sub>CB</sub> = 50V V <sub>CB</sub> = 50V, T <sub>A</sub> = +150°C
Emitter-Base Cut-Off Current	IEBO	_	1	20	nA	$V_{EB} = 6V$
Collector-Emitter Cut-Off Current	ICES	_	2	50	nA	$V_{CE} = 40V, V_{BE} = 0V$
Static Forward Current Transfer Ratio (Note 9)	hFE	200 200 150 80	329 329 305 233	600 —	_	$\label{eq:lc} \begin{array}{l} IC = 100 \text{mA}, \ V_{CE} = 2 V \\ I_{C} = 500 \text{mA}, \ V_{CE} = 2 V \\ I_{C} = 1 \text{A}, \ V_{CE} = 2 V \\ I_{C} = 2 \text{A}, \ V_{CE} = 2 V \end{array}$
Collector-Emitter Saturation Voltage (Note 9)	V <sub>CE(sat)</sub>	_	49 37 65 121 180	80 120 220 350 600	mV	$\begin{split} I_{C} &= 100 \text{mA}, I_{B} = 1 \text{mA} \\ I_{C} &= 500 \text{mA}, I_{B} = 50 \text{mA} \\ I_{C} &= 1 \text{A}, I_{B} = 100 \text{mA} \\ I_{C} &= 2 \text{A}, I_{B} = 200 \text{mA} \\ I_{C} &= 3 \text{A}, I_{B} = 300 \text{mA} \end{split}$
Base-Emitter Saturation Voltage (Note 9)	VBE(sat)	—	0.91	1.1	V	Ic = 1A, I <sub>B</sub> = 100mA
Base-Emitter Turn-On Voltage (Note 9)	VBE(on)	—	0.78	1	V	$I_C = 1A$ , $V_{CE} = 2V$
Input Capacitance	CIBO	—	160	_	pF	$V_{EB} = 0.5V$ , f = 1MHz
Output Capacitance	Сово	—	11		pF	V <sub>CB</sub> = 10V, f = 1MHz
Transition Frequency	fT	_	200	—	MHz	Ic = 50mA, Vce = 10V f = 100MHz
	tdelay	—	7.9	_	ns	
Switching Time	t <sub>rise</sub>	_	2.9	_	ns	$I_{C} = 1A, V_{CC} = 10V,$
	tstorage	—	728		ns	$I_{B1} = -I_{B2} = 100 \text{mA}$
	t <sub>fall</sub>	—	32.6	_	ns	

Note: 9. Measured under pulsed conditions. Pulse width  $\leq$  300µs. Duty cycle  $\leq$  2%.



# Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

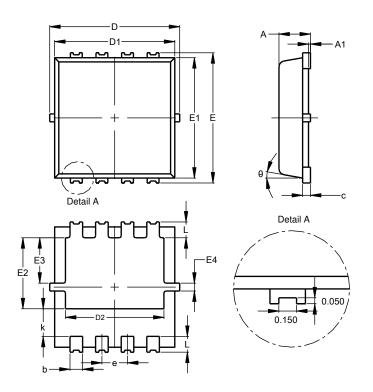




## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8 (SWP) (Type UX)

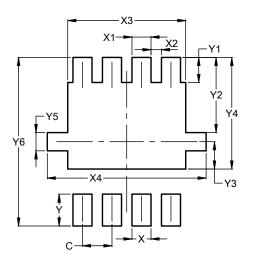


PowerDI3333-8 (SWP)					
(Type UX)					
Dim	Min	Max	Тур		
Α	0.75	0.85	0.80		
A1	0.00	0.05			
b	0.25	0.40	0.32		
С	0.10	0.25	0.15		
D	3.20	3.40	3.30		
D1	2.95	3.15	3.05		
D2	2.30	2.70	2.50		
Е	3.20	3.40	3.30		
E1	2.95	3.15	3.05		
E2	1.60	2.00	1.80		
E3	0.95	1.35	1.15		
E4	0.10	0.30	0.20		
e	-	_	0.65		
k	0.50	0.90	0.70		
L	0.30	0.50	0.40		
θ	0°	12°	10°		
All [	All Dimensions in mm				

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### PowerDI3333-8 (SWP) (Type UX)



Dimensions	Value (in mm)
С	0.650
Х	0.420
X1	0.420
X2	0.230
X3	2.600
X4	3.500
Y	0.700
Y1	0.550
Y2	1.650
Y3	0.600
Y4	2.450
Y5	0.400
Y6	3.700



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